TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

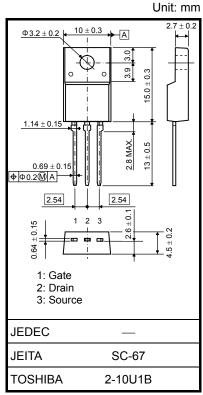
TK13A50D

Switching Regulator Applications

- Low drain-source ON resistance: $RDS(ON) = 0.31 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 7.5 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 500 \ V)$
- Enhancement-mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

| Characte | ristics | Symbol | Rating | Unit | |
|-------------------------|-----------------------|------------------|------------|------|--|
| Drain-source voltage | | V _{DSS} | 500 | V | |
| Gate-source voltage | | V _{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | Ι _D | 13 | Α | |
| | Pulse (Note 1) | I _{DP} | 52 | A . | |
| Drain power dissipation | on (Tc = 25°C) | PD | 45 | W | |
| Single pulse avalanch | ne energy (Note 2) | E _{AS} | 390 | mJ | |
| Avalanche current | | I _{AR} | 13 | А | |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 4.5 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature | range | T _{stg} | -55 to 150 | °C | |

Absolute Maximum Ratings (Ta = 25°C)



Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

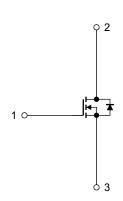
Thermal Characteristics

| Characteristics | Symbol | Max | Unit | |
|--|------------------------|------|------|--|
| Thermal resistance, channel to case | R _{th (ch-c)} | 2.78 | °C/W | |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W | |

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 3.92 mH, $R_G = 25 \Omega$, $I_{AR} = 13 \text{ A}$ Note 3: Repetitive rating: pulse width limited by maximum channel temperature This transistor is an electrostatic sensitive device. Please handle with caution.

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Internal Connection



Start of commercial production 2009-01

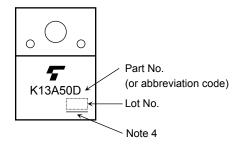
Electrical Characteristics (Ta = 25°C)

| Char | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|---------------|----------------------|--|-----|------|-----|------|
| Gate leakage current | | I _{GSS} | $V_{GS}=\pm 30~V,~V_{DS}=0~V$ | _ | — | ±1 | μA |
| Drain cut-off current | | I _{DSS} | $V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | _ | | 10 | μA |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 500 | | _ | V |
| Gate threshold v | oltage | V _{th} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ | 2.0 | | 4.0 | V |
| Drain-source ON | resistance | R _{DS (ON)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$ | | 0.31 | 0.4 | Ω |
| Forward transfer | admittance | Y _{fs} | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 6.5 \text{ A}$ | 1.9 | 7.5 | | S |
| Input capacitance | | C _{iss} | | _ | 1800 | _ | |
| Reverse transfer capacitance | | C _{rss} | V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz | _ | 9 | _ | pF |
| Output capacitance | | C _{oss} | | | 190 | | |
| Switching time | Rise time | tr | $ \begin{array}{c} 10 \text{ V} \\ \text{V}_{GS} \\ 0 \text{ V} \\ 50 \Omega \end{array} $ $ \begin{array}{c} \text{I}_{D} = 6.5 \text{ A} \text{ V}_{OUT} \\ \text{O} \\ \text{V}_{GS} \\ \text{V}_{DD} \approx 200 \text{ V} \end{array} $ | | 40 | | . ns |
| | Turn-on time | t _{on} | | | 80 | | |
| | Fall time | t _f | | | 15 | | |
| | Turn-off time | t _{off} | $v_{DD} \approx 200 v$ Duty $\leq 1\%$, t _w = 10 µs | | 110 | _ | |
| Total gate charge | | Qg | | _ | 38 | | |
| Gate-source charge | | Q _{gs} | $V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=13~A$ | _ | 24 | | nC |
| Gate-drain charge | | Q _{gd} |] | | 14 | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | — | _ | _ | 13 | А |
| Pulse drain reverse current (Note 1) | I _{DRP} | — | _ | _ | 52 | А |
| Forward voltage (diode) | V _{DSF} | $I_{DR} = 13 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 13 \text{ A}, V_{GS} = 0 \text{ V},$ | _ | 1200 | _ | ns |
| Reverse recovery charge | Q _{rr} | dl _{DR} /dt = 100 A/μs | _ | 13 | _ | μC |

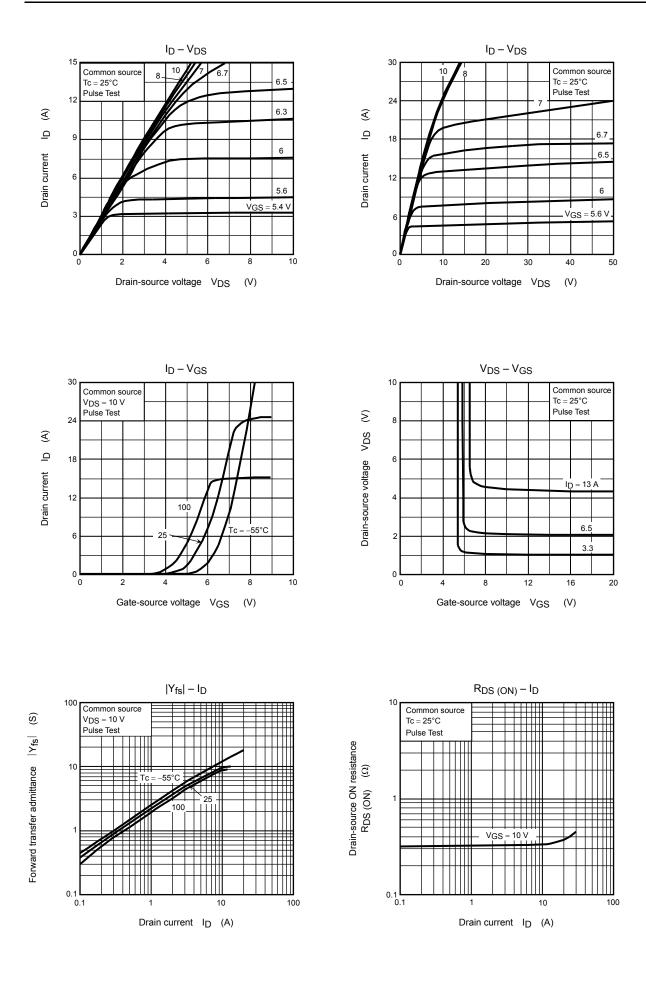
Marking



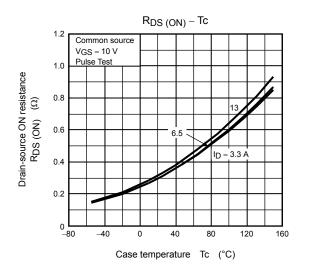
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

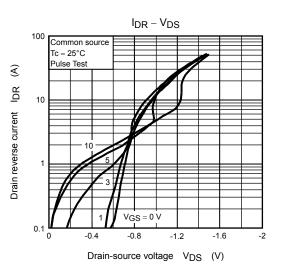
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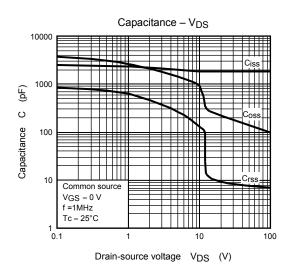
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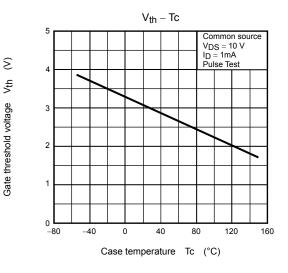


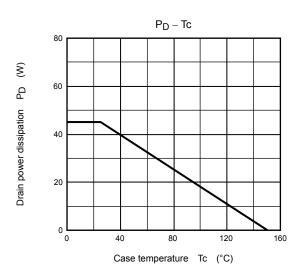
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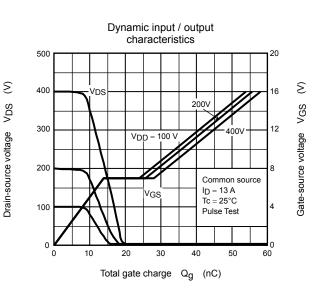


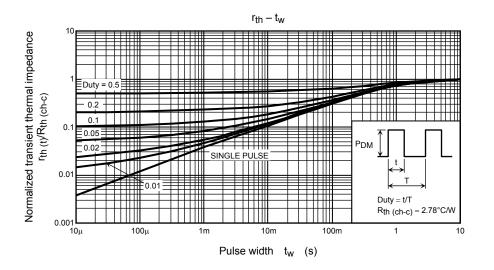


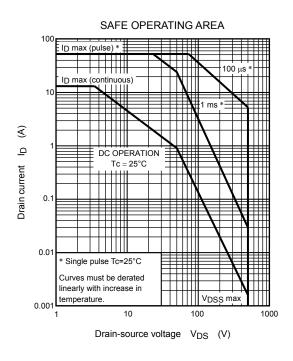


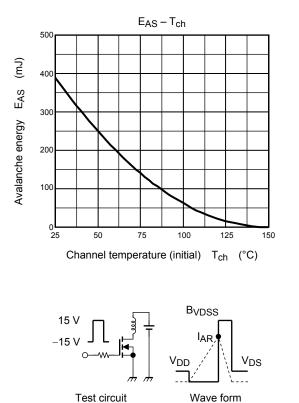












Test circuit

 $E_{AS} = \frac{1}{2} \cdot L \cdot l^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}}\right)$ $R_G = 25 \Omega$ V_{DD} = 90 V, L = 3.92 mH

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